

2SK2738

Silicon N Channel MOS FET
High Speed Power Switching

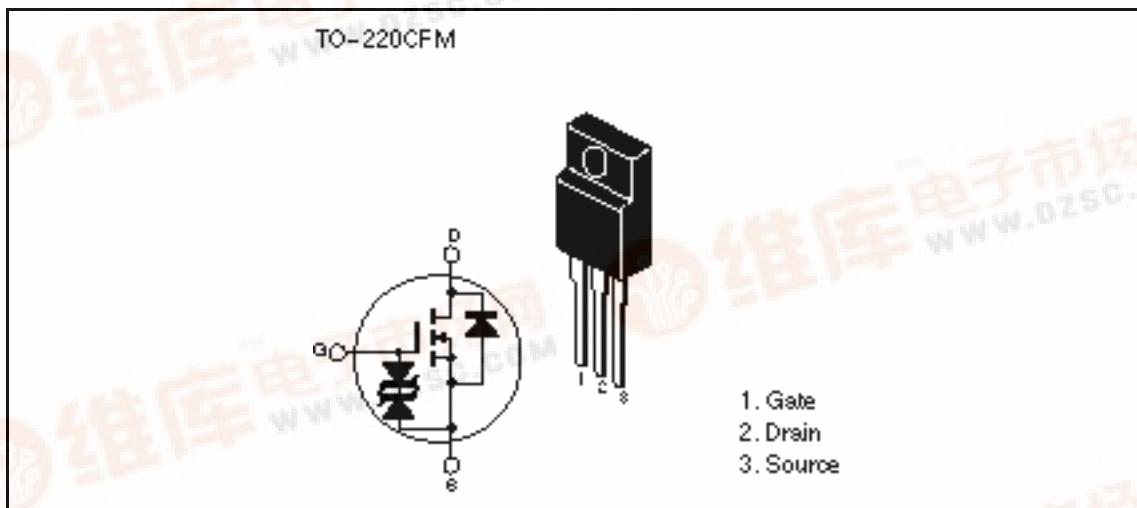
HITACHI

ADE-208-483
1st. Edition

Features

- Low on-resistance
 $R_{DS} = 15 \text{ m}\Omega$ typ
- High speed switching
- 4V gate drive device can be driven from 5V source

Outline



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Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	60	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	I _D	40	A
Drain peak current	I _{D(pulse)} ^{*1}	160	A
Body to drain diode reverse drain current	I _{DR}	40	A
Avalanche current	I _{AP} ^{*3}	40	A
Avalanche Energy	E _{AR} ^{*3}	137	mJ
Channel dissipation	Pch ^{*2}	30	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	−55 to +150	°C

Notes: 1. PW 10µs, duty cycle 1 %

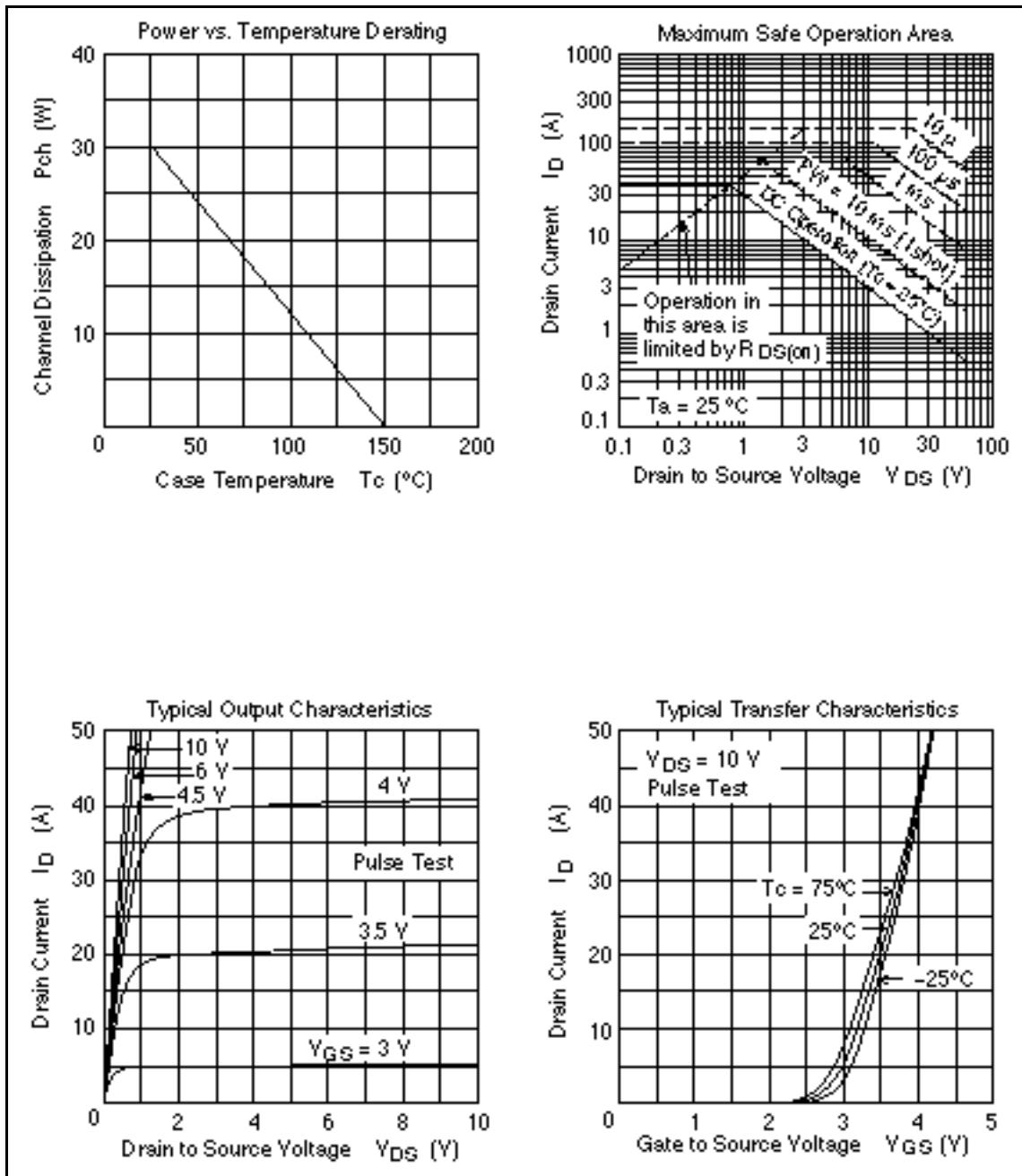
2. Value at Tc = 25°C

3. Value at Tch = 25°C, R_g = 50

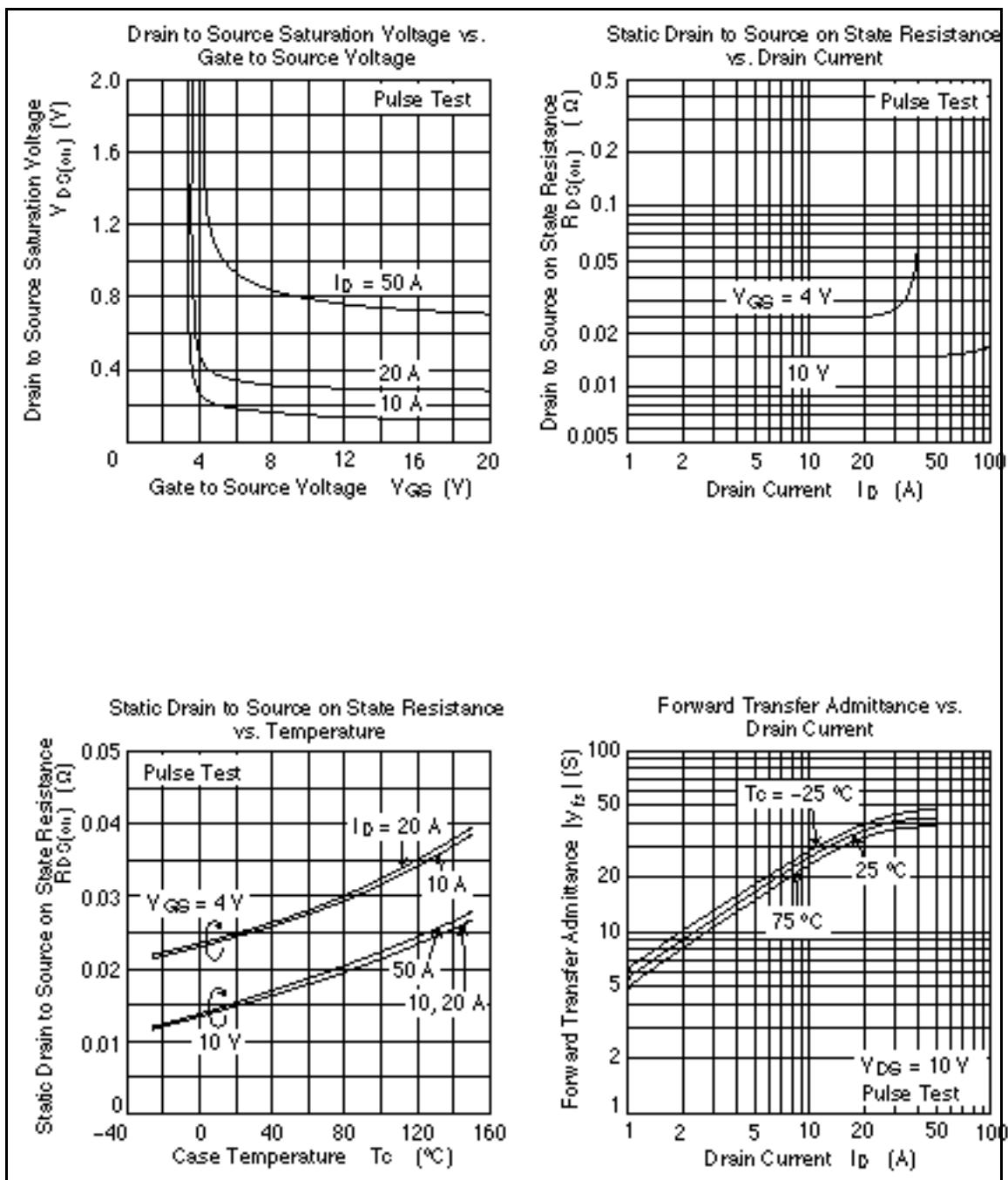
Electrical Characteristics (Ta = 25°C)

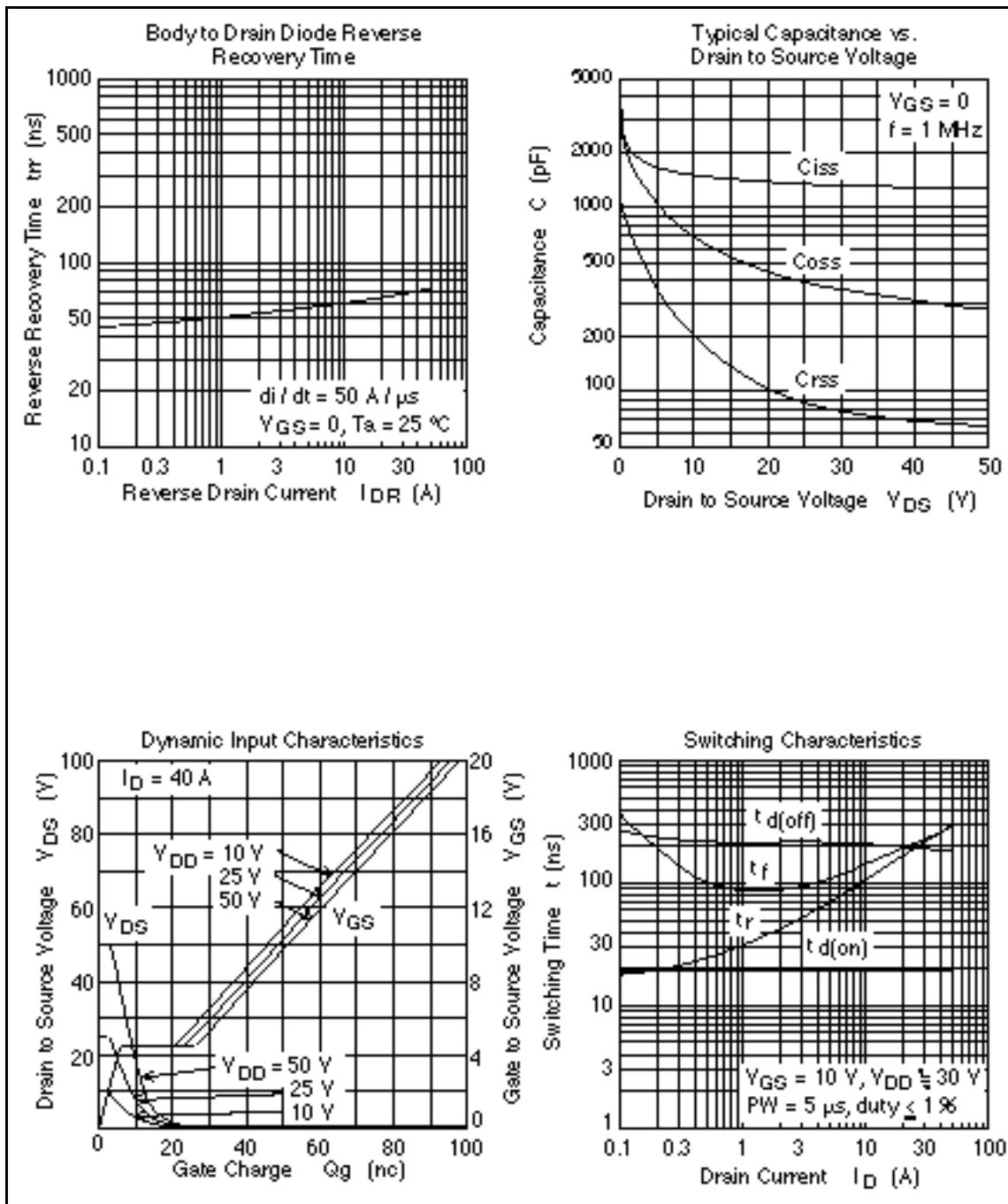
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR)DSS}	60	—	—	V	I _D = 10mA, V _{GS} = 0
Gate to source breakdown voltage	V _{(BR)GSS}	±20	—	—	V	I _G = ±100µA, V _{DS} = 0
Gate to source leak current	I _{GSS}	—	—	±10	µA	V _{GS} = ±16V, V _{DS} = 0
Zero gate voltage drain current	I _{DSS}	—	—	10	µA	V _{DS} = 60 V, V _{GS} = 0
Gate to source cutoff voltage	V _{GS(off)}	1.5	—	2.5	V	I _D = 1mA, V _{DS} = 10V
Static drain to source on state resistance	R _{DS(on)}	—	15	20	m	I _D = 20A, V _{GS} = 10V ^{*1}
Forward transfer admittance	y _{fs}	20	35	—	S	I _D = 20A, V _{DS} = 10V ^{*1}
Input capacitance	C _{iss}	—	1500	—	pF	V _{DS} = 10V
Output capacitance	C _{oss}	—	720	—	pF	V _{GS} = 0
Reverse transfer capacitance	C _{rss}	—	200	—	pF	f = 1MHz
Turn-on delay time	t _{d(on)}	—	20	—	ns	I _D = 20A, V _{GS} = 10V
Rise time	t _r	—	180	—	ns	R _L = 1.5
Turn-off delay time	t _{d(off)}	—	200	—	ns	
Fall time	t _f	—	200	—	ns	
Body to drain diode forward voltage	VDF	—	0.95	—	V	I _F = 40A, V _{GS} = 0 diF/dt = 50A/µs
Body to drain diode reverse recovery time	t _{rr}	—	70	—	V	I _F = 40A, V _{GS} = 0 diF/dt = 50A/µs

Note: 1. Pulse test

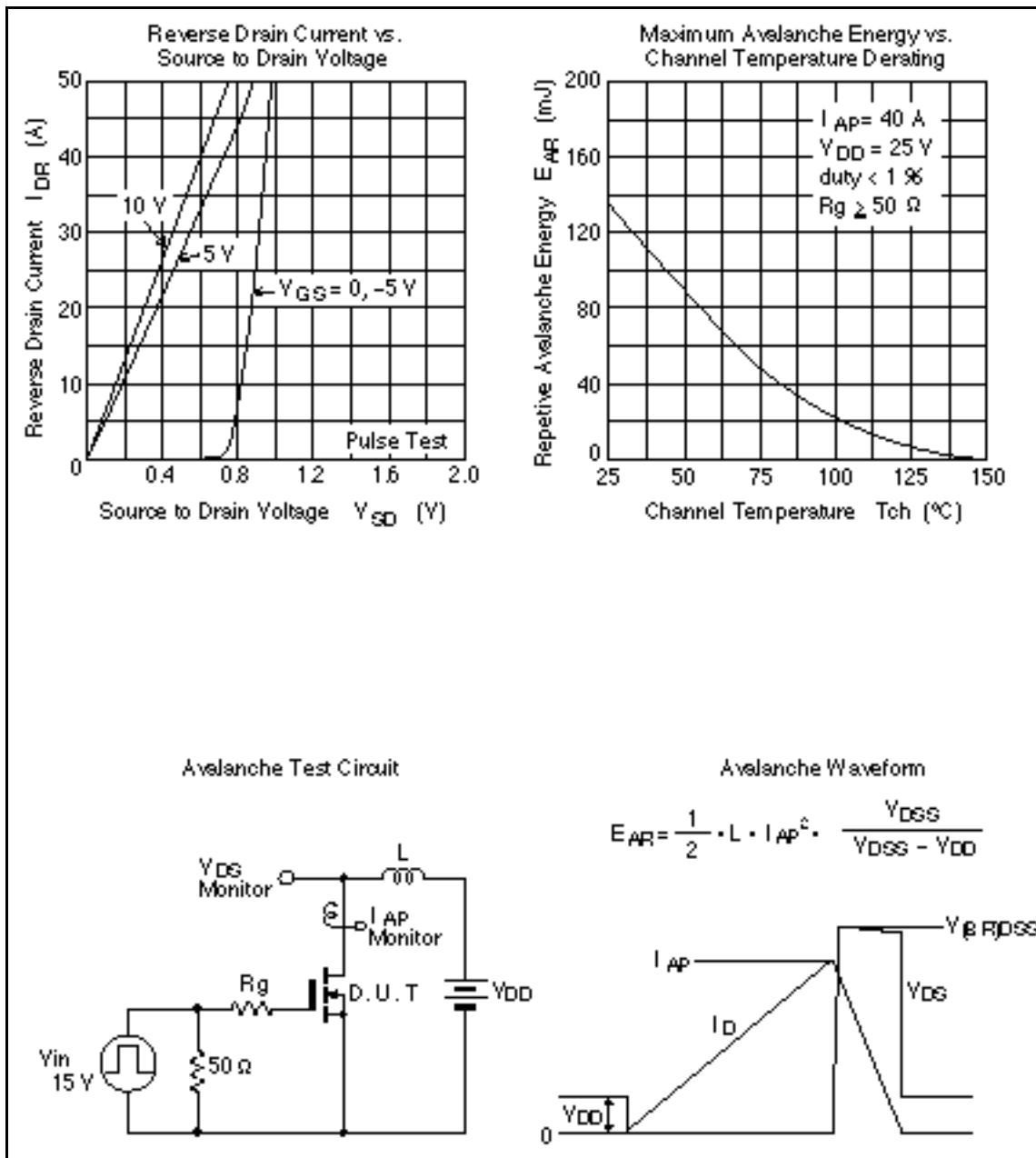
Main Characteristics

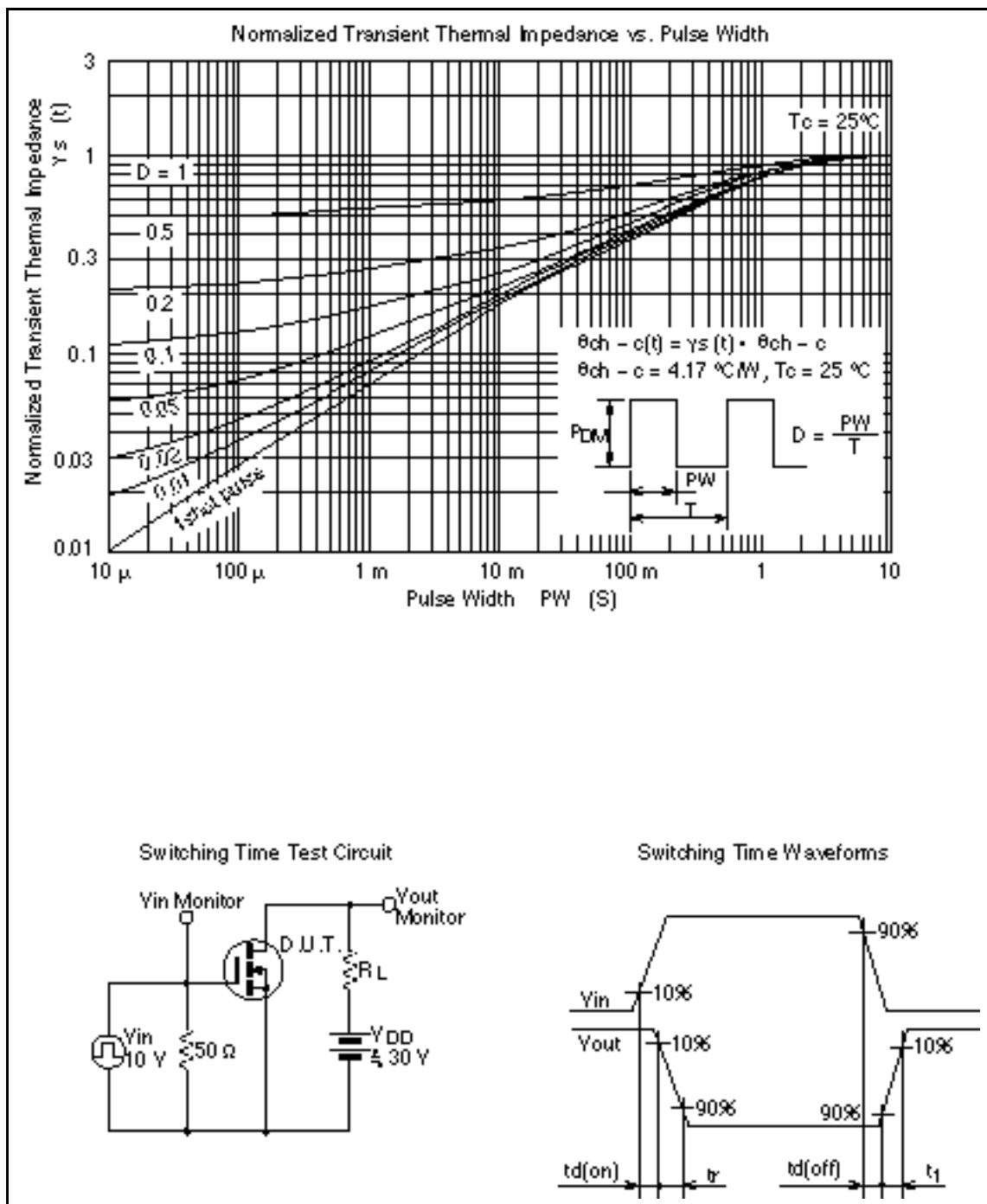
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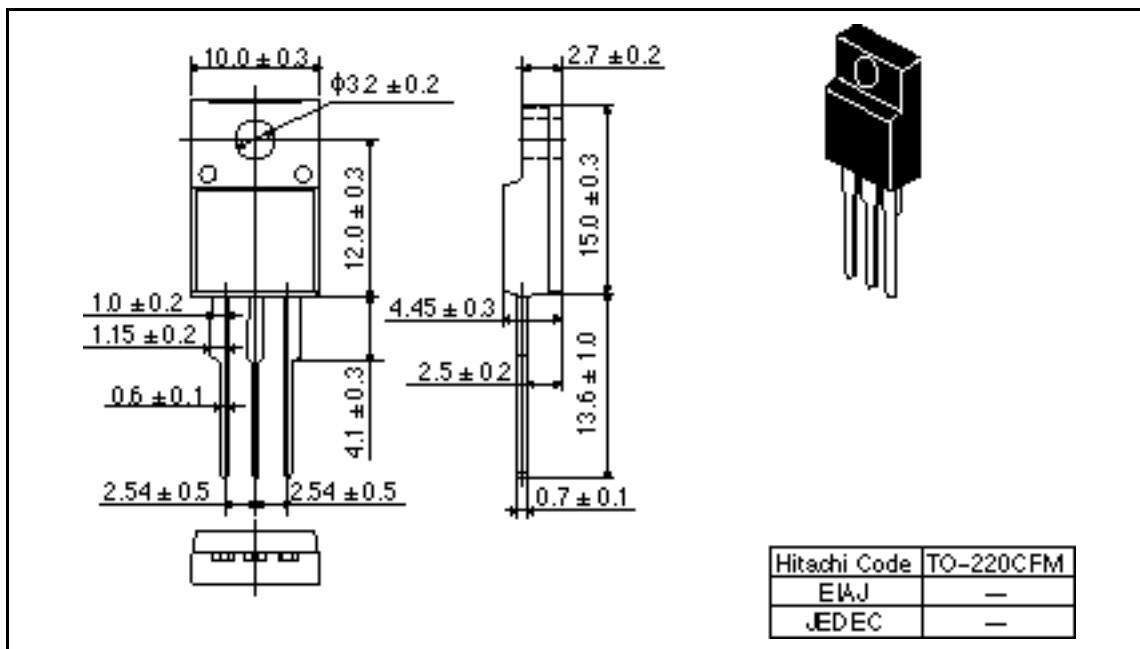




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Package Dimensions

Unit: mm



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